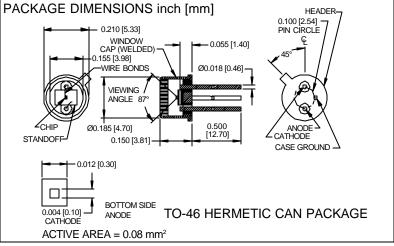
PHOTONIC DETECTORS INC.



Silicon Carbide (SiC), Ultra Violet (U.V.) Photodiode Type PDU-S101



FEATURES

• 0.14 A/W @ 280 nm

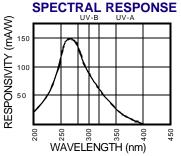
DESCRIPTION

- The PDU-S101 is a SiC, planar passivated
- U.V. photodiode. Spectral range from 200 • High shunt resistance
- 280 nm peak response nm to 400 nm with a 0.08 mm² active area.
- Packaged in a isolated TO-46 with U.V. • Short wavelength resp.
 - transmitting window can.

APPLICATIONS

- Flame detectors
- U.V. sensors
- U.V. monitors
- U.V. instrumentation

| ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted) | | | | | | | | |
|--|-----------------------------|-----|------|-------|--|--|--|--|
| SYMBOL | PARAMETER | MIN | MAX | UNITS | | | | |
| VBR | Reverse Voltage | | 20 | V | | | | |
| T _{STG} | Storage Temperature | -55 | +175 | °C | | | | |
| T _o | Operating Temperature Range | -40 | +125 | °C | | | | |
| T _s | Soldering Temperature* | | +240 | °C | | | | |
| Ι | Light Current | | 0.5 | mA | | | | |



*1/16 inch from case for 3 secs max

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|--------------------|----------------------------|--------------------------------|-----|-----------------------|-----|----------------|
| I _{sc} | Short Circuit Current | H = 1 SUN, 360 nm | 30 | 40 | | nA |
| I _D | Dark Current | $H = 0, V_{R} = 1 V$ | | 0.5 | 1.0 | nA |
| R _{sh} | Shunt Resistance | $H = 0, V_{R} = 10 \text{ mV}$ | 500 | 1000 | | $M\Omega$ |
| TC R _{SH} | RSH Temp. Coefficient | $H = 0, V_{R} = 10 \text{ mV}$ | | -8 | | % / °C |
| C | Junction Capacitance | $H = 0, V_{R} = 0 V^{**}$ | | 21 | 50 | pF |
| ∧range | Spectral Application Range | Spot Scan | 200 | | 400 | nm |
| λр | Spectral Response - Peak | Spot Scan | | 280 | | nm |
| V _{BR} | Breakdown Voltage | I = 10 µµA | 10 | 30 | | V |
| NEP | Noise Equivalent Power | V _R = 10 V @ Peak | | 1.5x10 ⁻¹⁴ | | W/ √ Hz |
| tr | Response Time | $RL = 1 K \Omega V_R = 10 V$ | | 5 | 10 | nS |

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. ** f = 1MHz [FORM NO 100-PDL-S101 REV [FORM NO. 100-PDU-S101 REV C]